GBJ10005 THRU GBJ1010

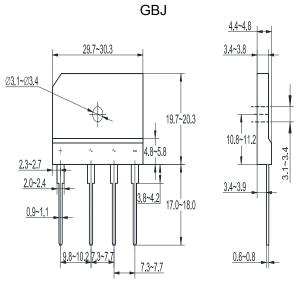
GLASS PASSIVATED SINGLE-PHASE BRIDGE RECTIFIER REVERSE VOLTAGE: 50 to 1000 V FORWARD CURRENT: 10 A

Features

- · Glass passivated chip junction
- · Ideal for printed circuit board
- · Low reverse leakage current
- · Low forward voltage drop
- · High surge current capability

Mechanical data

- · Case:Molded plastic, GBJ
- Epoxy: UL 94V-0 rate flame retardant
- Mounting Position: Any



Dimensions in inches and (millimeters)

Absolute Maximum Ratings and Characteristics

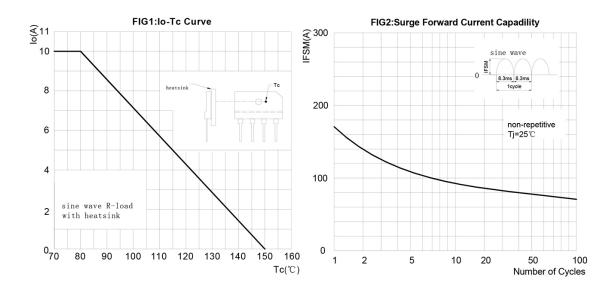
Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

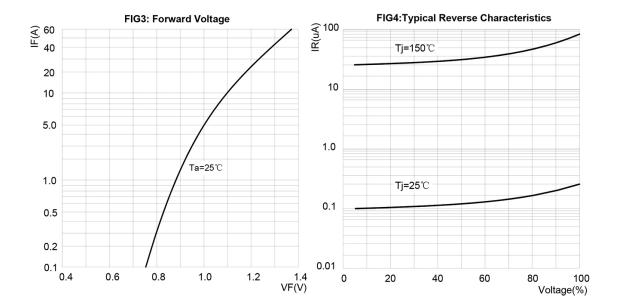
Parameter	Symbols	GBJ 10005	GBJ 1001	GBJ 1002	GBJ 1004	GBJ 1006	GBJ 1008	GBJ 1010	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current with Heatsink at T_c = 100 °C	I _(AV)	10							А
Peak Forward Surge Current, 8.3 ms Single Half-Sine -Wave superimposed on rated load (JEDEC Method)	I _{FSM}	170							А
Current Squared Time at 1 ms \leq t \leq 8.3 ms	l ² t	120							A ² S
Maximum Forward Voltage at 5 A DC	V _F	1.1							V
Maximum Reverse Current at $T_A = 25 \degree C$ at Rated DC Blocking Voltage $T_A = 125 \degree C$	I _R	10 500							μΑ
Typical Thermal Resistance, without heatsink	$R_{\theta JA}$	25							°C/W
Typical Thermal Resistance, with heatsink	$R_{\theta JC}$	2.3							°C/W
Operating and Storage Temperature Range	T_{J},T_{Stg}	- 55 to + 150							°C



TOP DYNAMIC

Dated : 16/08/2016 YJ Rev: 02







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